## NSN 5962-01-360-1359

Memory Microcircuit - Page 1 of 2



View Online at https://aerobasegroup.com/nsn/5962-01-360-1359

Body Length:
1.485 inches
Body Width:
Between 0.240 inches and 0.310 inches
Body Height:
0.215 inches
Maximum Power Dissipation Rating:
1.0 watts
Operating Tempurature Range:
-55.0/+125.0 degrees celsius
Storage Tempurature Range:
-65.0/+150.0 degrees celsius
End Application:
6625-01-260-2936
Features Provided:
Hermetically sealed and burn in and monolithic and positive outputs
Inclosure Material:
Ceramic
Inclosure Configuration:
Dual-in-line
Output Logic Form:
Complementary-metal oxide-semiconductor logic
Case Outline Source And Designator:
D-15 mil-m-38510
Current Rating Per Characteristic:
115.00 milliamperes reverse current, dc absolute
Terminal Surface Treatment:
Solder
Product Name:
Parallel 512 x 9 fifo
Voltage Rating And Type Per Characteristic:
-0.5 volts power source and 7.0 volts power source
Capitance Rating Per Characteristic:
8.00 input picofarads and 8.00 output picofarads
Time Rating Per Chacteristic:
65.00 nanoseconds access
Memory Device Type:
First-in first-out
Test Data Document:
96906-mil-std-883 standard (includes industry or association standards, individual manufactureer standards, etc.)
Terminal Type And Quantity:

28 printed circuit

## NSN 5962-01-360-1359

Memory Microcircuit - Page 2 of 2



_			•		
•	n	ο.	•	18	e:

N/a

**Unit Of Measure:** 

--

Demilitarization:

No

Fiig:

A458a0